



Integrated Device Technology, Inc.

FAST CMOS QUAD 2-INPUT MULTIPLEXER

IDT54/74FCT157T/AT/CT/DT
IDT54/74FCT257T/AT/CT/DT
IDT54/74FCT2257T/AT/CT

FEATURES:

- **Common features:**

- Low input and output leakage $\leq 1\mu\text{A}$ (max.)
- Extended commercial range of -40°C to $+85^\circ\text{C}$
- CMOS power levels
- True TTL input and output compatibility
 - $V_{OH} = 3.3\text{V}$ (typ.)
 - $V_{OL} = 0.3\text{V}$ (typ.)
- Meets or exceeds JEDEC standard 18 specifications
- Product available in Radiation Tolerant and Radiation Enhanced versions
- Military product compliant to MIL-STD-883, Class B and DESC listed (dual marked)
- Available in DIP, SOIC, SSOP, QSOP, TSSOP, CERPACK and LCC packages

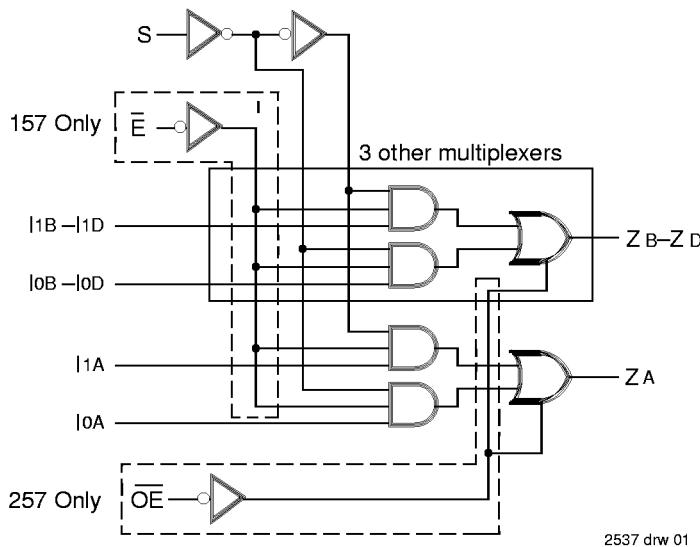
- **Features for FCT157T/257T:**

- Std., A, C and D speed grades
- High drive outputs (-15mA I_{OH} , 48mA I_{OL})

- **Features for FCT2257T:**

- Std., A, and C speed grades
- Resistor outputs (-15mA I_{OH} , 12mA I_{OL} Com.)
(-12mA I_{OH} , 12mA I_{OL} Mil.)
- Reduced system switching noise

FUNCTIONAL BLOCK DIAGRAM



DESCRIPTION:

The FCT157T, FCT257T/FCT2257T are high-speed quad 2-input multiplexers built using an advanced dual metal CMOS technology. Four bits of data from two sources can be selected using the common select input. The four buffered outputs present the selected data in the true (non-inverting) form.

The FCT157T has a common, active-LOW, enable input. When the enable input is not active, all four outputs are held LOW. A common application of 'FCT157T is to move data from two different groups of registers to a common bus. Another application is as a function generator. The 'FCT157T can generate any four of the 16 different functions of two variables with one variable common.

The FCT257T/FCT2257T have a common Output Enable (\bar{OE}) input. When \bar{OE} is HIGH, all outputs are switched to a high-impedance state allowing the outputs to interface directly with bus-oriented systems.

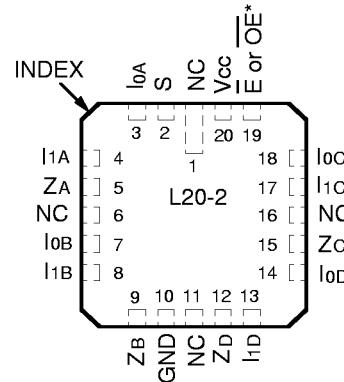
The FCT2257T has balanced output drive with current limiting resistors. This offers low ground bounce, minimal undershoot and controlled output fall times-reducing the need for external series terminating resistors. FCT2xxxT parts are plug-in replacements for FCTxxxT parts.

PIN CONFIGURATIONS

S	1	16	V _{cc}
I_{0A}	2	15	\bar{E} or \bar{OE}^*
I_{1A}	3	14	I_{OC}
Z _A	4	13	I_{1C}
I_{0B}	5	12	Z_C
I_{1B}	6	11	I_{OD}
Z _B	7	10	I_{1D}
GND	8	9	Z_D

DIP/SOIC/QSOP/CERPACK
TOP VIEW

2537 drw 02



2537 drw 03

* \bar{E} for FCT157, \bar{OE} for FCT257/FCT2257.

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MILITARY AND INDUSTRIAL TEMPERATURE RANGES

PIN DESCRIPTION

Pin Names	Description
I _{0A} -I _{0D}	Source 0 Data Inputs
I _{1A} -I _{1D}	Source 1 Data Inputs
\bar{E}	Enable Input (Active LOW)-FCT157T
\bar{OE}	Output Enable (Active LOW)-FCT257T/2257T
S	Select Input
Z _A -Z _D	Outputs

2537 tbl 01

FUNCTION TABLE⁽¹⁾

Inputs				Output Z _N	
\bar{E}/\bar{OE}	S	I ₀	I ₁	157	257
H	X	X	X	L	Z
L	H	X	L	L	L
L	H	X	H	H	H
L	L	L	X	L	L
L	L	H	X	H	H

NOTE:

1. H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Don't Care
- Z = High Impedance

2537 tbl 02

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to V _{CC} +0.5	V
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	-60 to +120	mA

NOTES:

2537 Ink 03

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed V_{CC} by +0.5V unless otherwise noted.
2. Input and V_{CC} terminals only.
3. Outputs and I/O terminals only.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	6	10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	8	12	pF

NOTE:

2537 Ink 04

1. This parameter is measured at characterization but not tested.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Commercial: TA = -40°C to $+85^{\circ}\text{C}$, Vcc = 5.0V \pm 5%; Military: TA = -55°C to $+125^{\circ}\text{C}$, Vcc = 5.0V \pm 10%

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I _{IH}	Input HIGH Current ⁽⁴⁾	VCC = Max.	VI = 2.7V	—	—	± 1	μA
I _{IL}	Input LOW Current ⁽⁴⁾		VI = 0.5V	—	—	± 1	
I _{OZH}	High Impedance Output Current	VCC = Max.	VO = 2.7V	—	—	± 1	μA
I _{OZL}	(3-State Output pins) ⁽⁴⁾		VO = 0.5V	—	—	± 1	
I _I	Input HIGH Current ⁽⁴⁾	VCC = Max., VI = VCC (Max.)		—	—	± 1	μA
V _{IK}	Clamp Diode Voltage	VCC = Min., I _{IN} = -18mA		—	-0.7	-1.2	V
V _H	Input Hysteresis	—		—	200	—	mV
I _{CC}	Quiescent Power Supply Current	VCC = Max., VIN = GND or VCC		—	0.01	1	mA

2537 Ink 05

OUTPUT DRIVE CHARACTERISTICS FOR FCT157/257T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
V _{OH}	Output HIGH Voltage	VCC = Min. VIN = VIH or VIL	I _{OH} = -6mA MIL. I _{OH} = -8mA COM'L.	2.4	3.3	—	V
			I _{OH} = -12mA MIL. I _{OH} = -15mA COM'L.	2.0	3.0	—	V
V _{OL}	Output LOW Voltage	VCC = Min. VIN = VIH or VIL	I _{OL} = 32mA MIL. I _{OL} = 48mA COM'L.	—	0.3	0.50	V
I _{OS}	Short Circuit Current	VCC = Max., VO = GND ⁽³⁾		-60	-120	-225	mA
I _{OFF}	Input/Output Power Off Leakage ⁽⁵⁾	VCC = 0V, VIN or VO $\leq 4.5\text{V}$		—	—	± 1	μA

2537 tbl 06

OUTPUT DRIVE CHARACTERISTICS FOR FCT2257T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
I _{ODL}	Output LOW Current	VCC = 5V, VIN = VIH or VIL, VOUT = 1.5V ⁽³⁾	—	16	48	—	mA
I _{ODH}	Output HIGH Current	VCC = 5V, VIN = VIH or VIL, VOUT = 1.5V ⁽³⁾	—	-16	-48	—	mA
V _{OH}	Output HIGH Voltage	VCC = Min. VIN = VIH or VIL	I _{OH} = -12mA MIL. I _{OH} = -15mA COM'L.	2.4	3.3	—	V
V _{OL}	Output LOW Voltage	VCC = Min. VIN = VIH or VIL	I _{OL} = 12mA	—	0.3	0.50	V

2537 Ink 07

NOTES:

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at Vcc = 5.0V, $+25^{\circ}\text{C}$ ambient.
- Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed one second.
- The test limit for this parameter is $\pm 5\mu\text{A}$ at TA = -55°C .
- This parameter is guaranteed but not tested.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾			Min.	Typ. ⁽²⁾	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = 3.4^{(3)}$			—	0.5	2.0	mA
I _{CCD}	Dynamic Power Supply Current ⁽⁴⁾	$V_{CC} = \text{Max.}$ Outputs Open \bar{E} or $\bar{OE} = \text{GND}$ One Bit Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	FCT _{xxxT}	—	0.15	0.25	mA/ MHz
				FCT2 _{xxxT}	—	0.06	0.12	
I _C	Total Power Supply Current ⁽⁶⁾	$V_{CC} = \text{Max.}$ Outputs Open $f_o = 10\text{MHz}$	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	FCT _{xxxT}	—	1.5	3.5	mA
				FCT2 _{xxxT}	—	0.6	2.2	
		50% Duty Cycle \bar{E} or $\bar{OE} = \text{GND}$ One Bit Toggling	$V_{IN} = 3.4$ $V_{IN} = \text{GND}$	FCT _{xxxT}	—	1.8	4.5	
				FCT2 _{xxxT}	—	0.9	3.2	
		$V_{CC} = \text{Max.}$ Outputs Open $f_o = 2.5\text{MHz}$	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	FCT _{xxxT}	—	1.5	3.5 ⁽⁵⁾	
				FCT2 _{xxxT}	—	0.6	2.2 ⁽⁵⁾	
		50% Duty Cycle \bar{E} or $\bar{OE} = \text{GND}$ Four Bits Toggling	$V_{IN} = 3.4$ $V_{IN} = \text{GND}$	FCT _{xxxT}	—	2.5	7.5 ⁽⁵⁾	
				FCT2 _{xxxT}	—	1.6	6.2 ⁽⁵⁾	

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NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 5.0\text{V}$, +25°C ambient.
3. Per TTL driven input ($V_{IN} = 3.4\text{V}$); all other inputs at V_{CC} or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

6. $I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$

$$I_C = I_{CC} + \Delta I_{CC} D_{HNT} + I_{CCD} (f_o N_o)$$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input ($V_{IN} = 3.4\text{V}$)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Output Transition Pair (HLH or LHL)

f_o = Output Frequency

N_O = Number of Outputs at f_o

All currents are in millamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - FCT157T

Symbol	Parameter	Condition ⁽¹⁾	FCT157T				FCT157AT				Unit	
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.								
tPLH	Propagation Delay IN to ZN	CL = 50pF RL = 500Ω	1.5	6.0	1.5	7.0	1.5	5.0	1.5	5.8	ns	
tPHL	Propagation Delay \bar{E} to ZN		1.5	10.5	1.5	12.0	1.5	6.0	1.5	7.4	ns	
tPLH	Propagation Delay S to ZN		1.5	10.5	1.5	12.0	1.5	7.0	1.5	8.1	ns	

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Symbol	Parameter	Condition ⁽¹⁾	FCT157CT				FCT157DT				Unit	
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.								
tPLH	Propagation Delay IN to ZN	CL = 50pF RL = 500Ω	1.5	4.3	1.5	5.0	1.5	3.9	—	—	ns	
tPHL	Propagation Delay \bar{E} to ZN		1.5	4.8	1.5	5.9	1.5	4.4	—	—	ns	
tPLH	Propagation Delay S to ZN		1.5	5.2	1.5	6.0	1.5	4.6	—	—	ns	

2537 tbl 08

SWITCHING CHARACTERISTICS OVER OPERATING RANGE – FCT257/2257T

Symbol	Parameter	Condition ⁽¹⁾	FCT257/2257T				FCT257/2257AT				Unit	
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.								
tPLH	Propagation Delay IN to ZN	CL = 50pF RL = 500Ω	1.5	6.0	1.5	7.0	1.5	5.0	1.5	5.8	ns	
tPHL	Propagation Delay S to ZN		1.5	10.5	1.5	12.0	1.5	7.0	1.5	8.1	ns	
tpZH	Output Enable Time		1.5	8.5	1.5	10.0	1.5	7.0	1.5	8.0	ns	
tPHZ	Output Disable Time		1.5	6.0	1.5	8.0	1.5	5.5	1.5	5.8	ns	

2537 tbl 09

Symbol	Parameter	Condition ⁽¹⁾	FCT257/2257CT				FCT257DT				Unit	
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.								
tPLH	Propagation Delay IN to ZN	CL = 50pF RL = 500Ω	1.5	4.3	1.5	5.0	1.5	3.9	—	—	ns	
tPHL	Propagation Delay S to ZN		1.5	5.2	1.5	6.0	1.5	4.4	—	—	ns	
tpZH	Output Enable Time		1.5	6.0	1.5	6.8	1.5	4.4	—	—	ns	
tPHZ	Output Disable Time		1.5	5.0	1.5	5.3	1.5	4.4	—	—	ns	

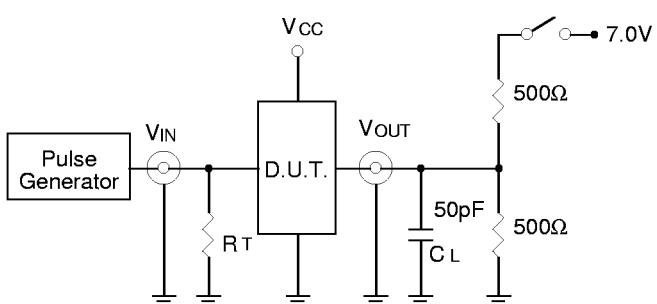
NOTES:

- See test circuits and waveforms.
- Minimum limits are guaranteed but not tested on Propagation Delay.

2537 tbl 10

TEST CIRCUITS AND WAVEFORMS

TEST CIRCUITS FOR ALL OUTPUTS



2537 drw 04

SWITCH POSITION

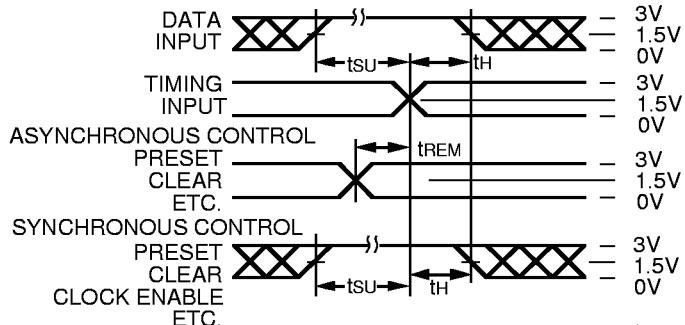
Test	Switch
Open Drain	Closed
Disable Low	
Enable Low	
All Other Tests	Open

DEFINITIONS: 2537 Lnk 11

C_L = Load capacitance: includes jig and probe capacitance.

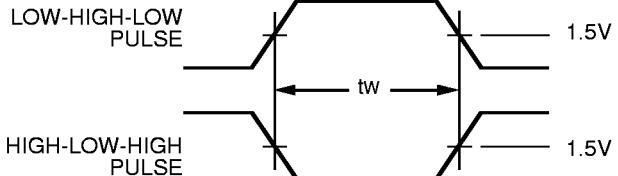
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

SET-UP, HOLD AND RELEASE TIMES



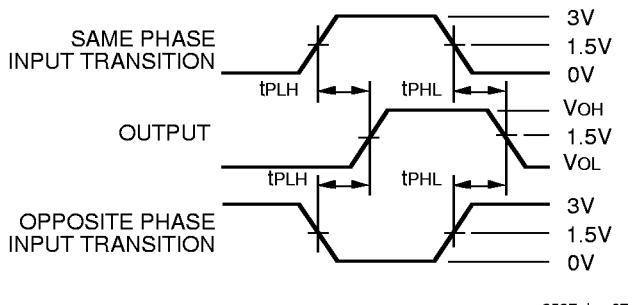
2537 drw 05

PULSE WIDTH



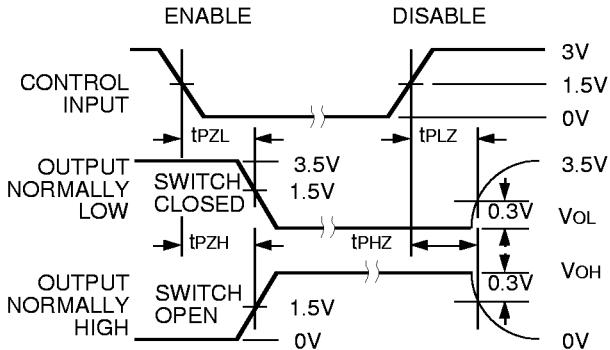
2537 drw 06

PROPAGATION DELAY



2537 drw 07

ENABLE AND DISABLE TIMES



2537 drw 08

NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH
2. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_F \leq 2.5\text{ns}$; $t_R \leq 2.5\text{ns}$

ORDERING INFORMATION

IDT	XX	FCT	X	XXXX	X	X	
Temperature Range		Family		Device Type	Package	Process	
						Blank	Commercial
						B	MIL-STD-883, Class B
					P	Plastic DIP	
					D	CERDIP	
					SO	Small Outline IC	
					L	Leadless Chip Carrier	
					E	CERPACK	
					Q	Quarter-size Small Outline Package	
					157T	Quad 2-Input Multiplexer	
					257T	Quad 2-Input Multiplexer (3-state)	
					157AT		
					257AT		
					157CT		
					257CT		
					157DT		
					257DT		
					Blank	High Drive	
					2	Balanced Drive	
					54	-55°C to +125°C	
					74	-40°C to +85°C	

2537 drw 09